

# 1 GHz, 5,500 V/μs **Low Distortion Amplifier**

# AD8009

#### **FEATURES**

**Ultrahigh Speed** 5,500 V/ $\mu$ s Slew Rate, 4 V Step, G = +2

545 ps Rise Time, 2 V Step, G = +2Large Signal Bandwidth

440 MHz, G = +2

320 MHz, G = +10

Small Signal Bandwidth (-3 dB)

1 GHz, G = +1

700 MHz, G = +2

Settling Time 10 ns to 0.1%, 2 V Step, G = +2

Low Distortion over Wide Bandwidth

-66 dBc @ 20 MHz, Second Harmonic

-75 dBc @ 20 MHz, Third Harmonic

Third Order Intercept (3IP)

26 dBm @ 70 MHz, G = +10

**Good Video Specifications** 

Gain Flatness 0.1 dB to 75 MHz

0.01% Differential Gain Error,  $R_L$  = 150  $\Omega$ 

0.01° Differential Phase Error,  $R_L$  = 150  $\Omega$ 

**High Output Drive** 

175 mA Output Load Drive

10 dBm with -38 dBc SFDR @ 70 MHz, G = +10

**Supply Operation** 

+5 V to ±5 V Voltage Supply

14 mA (Typ) Supply Current

#### **APPLICATIONS**

**Pulse Amplifier** 

IF/RF Gain Stage/Amplifiers

**High Resolution Video Graphics** 

**High Speed Instrumentations** 

**CCD Imaging Amplifier** 

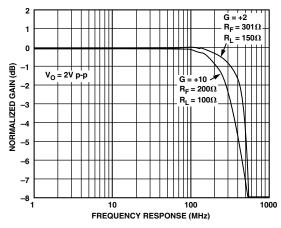


Figure 1. Large Signal Frequency Response; G = +2 and +10

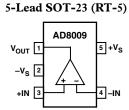
#### REV. F

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#### FUNCTIONAL BLOCK DIAGRAMS

8-Lead Plastic SOIC (R-8)

AD8009 NC 1 8 NC 7 +V<sub>S</sub> 6 ООТ 5 NC



#### PRODUCT DESCRIPTION

NC = NO CONNECT

The AD8009 is an ultrahigh speed current feedback amplifier with a phenomenal 5,500 V/µs slew rate that results in a rise time of 545 ps, making it ideal as a pulse amplifier.

The high slew rate reduces the effect of slew rate limiting and results in the large signal bandwidth of 440 MHz required for high resolution video graphic systems. Signal quality is maintained over a wide bandwidth with worst-case distortion of -40 dBc @ 250 MHz (G = +10, 1 V p-p). For applications with multitone signals, such as IF signal chains, the third order intercept (3IP) of 12 dBm is achieved at the same frequency. This distortion performance coupled with the current feedback architecture make the AD8009 a flexible component for a gain stage amplifier in IF/RF signal chains.

The AD8009 is capable of delivering over 175 mA of load current and will drive four back terminated video loads while maintaining low differential gain and phase error of 0.02% and 0.04°, respectively. The high drive capability is also reflected in the ability to deliver 10 dBm of output power @ 70 MHz with -38 dBc SFDR.

The AD8009 is available in a small SOIC package and will operate over the industrial temperature range -40°C to +85°C. The AD8009 is also available in an SOT-23-5 and will operate over the commercial temperature range of 0°C to 70°C.

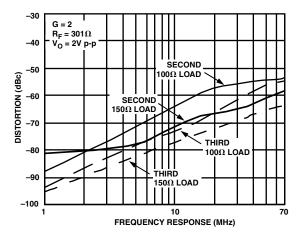


Figure 2. Distortion vs. Frequency; G = +2

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# **AD8009\* Product Page Quick Links**

Last Content Update: 11/01/2016

### Comparable Parts

View a parametric search of comparable parts

### Evaluation Kits <a> □</a>

 Universal Evaluation Board for Single High Speed Operational Amplifiers

### Documentation <a>□</a>

#### **Application Notes**

- AN-214: Ground Rules for High Speed Circuits
- AN-356: User's Guide to Applying and Measuring Operational Amplifier Specifications
- AN-649: Using the Analog Devices Active Filter Design Tool
- AN-692: Universal Precision Op Amp Evaluation Board

#### **Data Sheet**

 AD8009: 1 GHz, 5,500 V/µs Low Distortion Amplifier Data Sheet

#### **User Guides**

- UG-755: 8-Lead SOIC Amplifier Evaluation Board User Guide
- UG-838: Evaluation Board for Single, High Speed Op Amps Offered in 5-Lead SOT-23 and 6-Lead SOT-23 Packages

### Tools and Simulations

- · Analog Filter Wizard
- · Analog Photodiode Wizard
- AD8009 SPICE Macro-Model

### Reference Materials

#### **Product Selection Guide**

• High Speed Amplifiers Selection Table

#### **Tutorials**

- MT-034: Current Feedback (CFB) Op Amps
- MT-051: Current Feedback Op Amp Noise Considerations
- MT-057: High Speed Current Feedback Op Amps
- MT-059: Compensating for the Effects of Input Capacitance on VFB and CFB Op Amps Used in Current-to-Voltage Converters

## Design Resources <a>□</a>

- AD8009 Material Declaration
- · PCN-PDN Information
- · Quality And Reliability
- · Symbols and Footprints

### Discussions <a>□</a>

View all AD8009 EngineerZone Discussions

### Sample and Buy -

Visit the product page to see pricing options

### Technical Support -

Submit a technical question or find your regional support number

<sup>\*</sup> This page was dynamically generated by Analog Devices, Inc. and inserted into this data sheet. Note: Dynamic changes to the content on this page does not constitute a change to the revision number of the product data sheet. This content may be frequently modified.

# $\begin{array}{l} \textbf{AD8009-SPECIFICATIONS} \\ \textbf{(@ T_A=25^\circ\text{C}, V_S=\pm5 \text{ V}, R_L=100 \ \Omega; for R Package: R_F=301 \ \Omega \text{ for G}=+1, +2, } \\ \textbf{R_F=200 \ \Omega \text{ for G}=+10; for RT Package: R_F=332 \ \Omega \text{ for G}=+1, R_F=226 \ \Omega \text{ for G}=+2 \text{ and R}_F=191 \Omega \text{ for G}=+10, \text{ unless otherwise noted.)} \\ \end{array}$

		AD8009AR/JRT			
Model	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
$-3$ dB Small Signal Bandwidth, $V_0 = 0.2 \text{ V p-p}$					
R Package	$G = +1, R_F = 301 \Omega$		1,000		MHz
RT Package	$G = +1$ , $R_F = 332 \Omega$		845		MHz
Tel Tuolingo	G = +2	480	700		MHz
	G = +10	300	350		MHz
Large Signal Bandwidth, $V_0 = 2 \text{ V p-p}$	G = +10 G = +2	390	440		MHz
Large Signal Bandwidth, $v_0 - 2 v p-p$					
	G = +10	235	320		MHz
Gain Flatness 0.1 dB, $V_0 = 0.2 \text{ V p-p}$	$G = +2, R_L = 150 \Omega$	45	75 		MHz
Slew Rate	$G = +2$ , $R_L = 150 \Omega$ , 4 V Step	4,500	5,500		V/µs
Settling Time to 0.1%	$G = +2, R_L = 150 \Omega, 2 \text{ V Step}$		10		ns
	G = +10, 2  V Step		25		ns
Rise and Fall Time	$G = +2$ , $R_L = 150 \Omega$ , 4 V Step		0.725		ns
HARMONIC/NOISE PERFORMANCE					
Second Harmonic $G = +2$ , $V_O = 2 \text{ V p-p}$	10 MHz		-73		dBc
	20 MHz		-66		dBc
	70 MHz		-56		dBc
Third Harmonic	10 MHz		-77		dBc
	20 MHz		-75		dBc
	70 MHz		-58		dBc
Third Order Intercept (3IP)	70 MHz		26		dBm
W.R.T. Output, $G = +10$	150 MHz		18		dBm
w.K.1. Output, G = +10					
T XY 1. XY 1	250 MHz		12		dBm
Input Voltage Noise	f = 10 MHz		1.9		nV/√ <u>Hz</u>
Input Current Noise	f = 10 MHz, +In		46		pA/√ <u>Hz</u>
	–In		41		pA/√Hz
Differential Gain Error	NTSC, G = +2, $R_L$ = 150 $\Omega$		0.01	0.03	%
	$R_L = 37.5 \Omega$		0.02	0.05	%
Differential Phase Error	NTSC, G = +2, $R_L$ = 150 Ω		0.01	0.03	Degrees
	$R_L = 37.5 \Omega$		0.04	0.08	Degrees
DC PERFORMANCE					
Input Offset Voltage			2	5	mV
	$T_{MIN}$ to $T_{MAX}$			7	mV
Offset Voltage Drift			4		μV/°C
-Input Bias Current			50	150	±µA
	T <sub>MIN</sub> to T <sub>MAX</sub>		75		±μA
+Input Bias Voltage	1 MIN to 1 MAX		50	150	±μA
imput bius voituge	T <sub>MIN</sub> to T <sub>MAX</sub>		75	150	±μA
Open-Loop Transresistance	1 MIN to 1 MAX	90	250		$k\Omega$
Open-Loop Transfesistance	T <sub>MIN</sub> to T <sub>MAX</sub>	90	170		kΩ
INDUSTROLLA DA OTERIOTIOS	1 MIN to 1 MAX		110		Na2
INPUT CHARACTERISTICS			**^		1.0
Input Resistance	+Input		110		kΩ
	-Input		8		Ω
Input Capacitance	+Input		2.6		pF
Input Common-Mode Voltage Range			3.8		±V
Common-Mode Rejection Ratio	$V_{CM} = \pm 2.5$	50	52		dB
OUTPUT CHARACTERISTICS					
Output Voltage Swing		±3.7	$\pm 3.8$		V
Output Current	$R_L = 10 \Omega$ , $P_D$ Package = 0.7 W	150	175		mA
Short-Circuit Current			330		mA
POWER SUPPLY					
Operating Range		+5		±6	V
Quiescent Current		. ,	14	16	mA
Quiescent Gurrent	T <sub>MIN</sub> to T <sub>MAX</sub>		14	18	mA
Power Supply Rejection Ratio	$V_S = \pm 4 \text{ V to } \pm 6 \text{ V}$	64	70	10	dB
1 ower Supply Rejection Rano	VS-14 V LO TO V	04	10		uD

Specifications subject to change without notice.

# $\begin{tabular}{ll} \textbf{SPECIFICATIONS} & (@ T_A = 25 ^\circ C, V_S = +5 \ V, R_L = 100 \ \Omega, \ \text{for R Package: } R_F = 301 \ \Omega \ \text{for G} = +1, \ +2, \\ R_F = 200 \ \Omega \ \text{for G} = +10). \\ \end{tabular}$

		AD8009AR/JRT			
Model	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
-3 dB Small Signal Bandwidth, V <sub>O</sub> = 0.2 V p-p					
	$G = +1, R_F = 301 \Omega$		630		MHz
	G = +2		430		MHz
	G = +10		300		MHz
Large Signal Bandwidth, $V_0 = 2 V p-p$	G = +2		365		MHz
	G = +10		250		MHz
Gain Flatness 0.1 dB, $V_0 = 0.2 \text{ V p-p}$	$G = +2, R_L = 150 \Omega$		65		MHz
Slew Rate	$G = +2$ , $R_L = 150 Ω$ , 4 V Step		2,100		V/µs
Settling Time to 0.1%	$G = +2$ , $R_L = 150 Ω$ , 2 V Step		10		ns
	G = +10, 2  V Step		25		ns
Rise and Fall Time	$G = +2$ , $R_L = 150 \Omega$ , 4 V Step		0.725		ns
HARMONIC/NOISE PERFORMANCE					
Second Harmonic $G = +2$ , $V_O = 2 \text{ V p-p}$	10 MHz		-74		dBc
, , ,	20 MHz		-67		dBc
	70 MHz		-48		dBc
Third Harmonic	10 MHz		-76		dBc
	20 MHz		-72		dBc
	70 MHz		-44		dBc
Input Voltage Noise	f = 10 MHz		1.9		$nV/\sqrt{Hz}$
Input Current Noise	f = 10  MHz, +In		46		pA/√ <u>Hz</u>
	–In		41		pA/√ <del>Hz</del>
DC PERFORMANCE					
Input Offset Voltage			1	4	mV
-Input Bias Current			50	150	±μΑ
+Input Bias Voltage			50	150	±μA
INPUT CHARACTERISTICS					
Input Resistance	+Input		110		kΩ
input resistance	-Input		8		Ω
Input Capacitance	+Input		2.6		pF
Input Common-Mode Voltage Range			1.2 to 3	3.8	V
Common-Mode Rejection Ratio	$V_{CM} = 1.5 \text{ V to } 3.5 \text{ V}$	50	52		dB
OUTPUT CHARACTERISTICS					
Output Voltage Swing			1.1 to 3	3 0	V
Output Voltage Swing Output Current	$R_L = 10 \Omega$ , $P_D$ Package = 0.7 W		1.1 to .	J.9	mA
Short-Circuit Current	10 22, 1 D 1 ackage = 0.7 w		330		mA
			330		11111
POWER SUPPLY				1.6	X7
Operating Range		+5	10	±6	V
Quiescent Current	V - 45 V - 5 5 V	(4	10	12	mA
Power Supply Rejection Ratio	$V_S = 4.5 \text{ V to } 5.5 \text{ V}$	64	70		dB

Specifications subject to change without notice.

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#### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Supply Voltage
Internal Power Dissipation <sup>2</sup>
Small Outline Package (R) 0.75 W
Input Voltage (Common-Mode) $\pm V_S$
Differential Input Voltage±3.5 V
Output Short-Circuit Duration
Oh

..... Observe Power Derating Curves Storage Temperature Range R Package ....  $-65^{\circ}$ C to  $+125^{\circ}$ C Operating Temperature Range (A Grade) ....  $-40^{\circ}$ C to  $+85^{\circ}$ C Operating Temperature Range (J Grade) ....  $0^{\circ}$ C to  $70^{\circ}$ C Lead Temperature Range (Soldering 10 sec) ....  $300^{\circ}$ C

#### NOTES

<sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### MAXIMUM POWER DISSIPATION

The maximum power that can be safely dissipated by the AD8009 is limited by the associated rise in junction temperature. The maximum safe junction temperature for plastic encapsulated devices is determined by the glass transition temperature of the plastic, approximately 150°C. Exceeding this limit temporarily may cause a shift in parametric performance due to a change in the stresses exerted on the die by the package. Exceeding a junction temperature of 175°C for an extended period can result in device failure.

While the AD8009 is internally short circuit protected, this may not be sufficient to guarantee that the maximum junction temperature (150°C) is not exceeded under all conditions. To ensure proper operation, it is necessary to observe the maximum power derating curves.

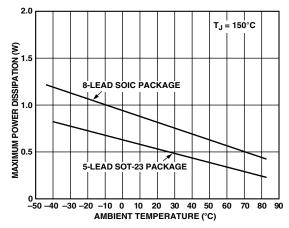


Figure 3. Plot of Maximum Power Dissipation vs. Temperature

#### **ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option	Branding	
AD8009AR	–40°C to +85°C	8-Lead SOIC	R-8		
AD8009AR-REEL	$-40^{\circ}$ C to $+85^{\circ}$ C	8-Lead SOIC	R-8		
AD8009AR-REEL7	$-40^{\circ}$ C to $+85^{\circ}$ C	8-Lead SOIC	R-8		
AD8009ARZ*	$-40^{\circ}$ C to $+85^{\circ}$ C	8-Lead SOIC	R-8		
AD8009ARZ-REEL*	$-40^{\circ}$ C to $+85^{\circ}$ C	8-Lead SOIC	R-8		
AD8009ARZ-REEL7*	$-40^{\circ}$ C to $+85^{\circ}$ C	8-Lead SOIC	R-8		
AD8009JRT-R2	0°C to 70°C	5-Lead SOT-23	RT-5	HKJ	
AD8009JRT-REEL	0°C to 70°C	5-Lead SOT-23	RT-5	HKJ	
AD8009JRT-REEL7	0°C to 70°C	5-Lead SOT-23	RT-5	HKJ	
AD8009JRTZ-REEL*	0°C to 70°C	5-Lead SOT-23	RT-5	HKJ	
AD8009JRTZ-REEL7*	0°C to 70°C	5-Lead SOT-23	RT-5	HKJ	
AD8009ACHIPS		Die			

<sup>\*</sup>Z = Pb-free part.

#### CAUTION\_

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8009 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



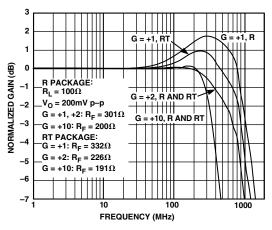
–4– REV. F

<sup>&</sup>lt;sup>2</sup>Specification is for device in free air:

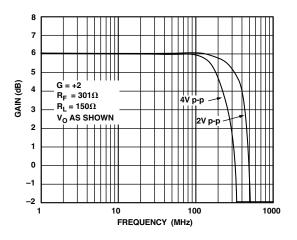
<sup>8-</sup>Lead SOIC Package:  $\theta_{JA} = 155^{\circ}\text{C/W}$ .

<sup>5-</sup>Lead SOT-23 Package:  $\theta_{IA} = 240^{\circ}$ C/W.

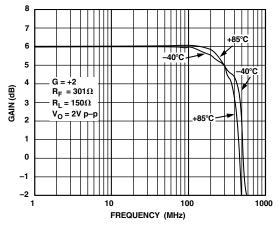
# **Typical Performance Characteristics—AD8009**



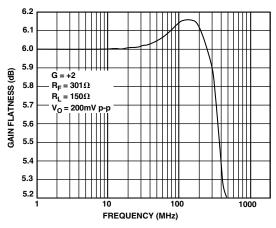
TPC 1. Frequency Response; G = +1, +2, +10, R and RT Packages



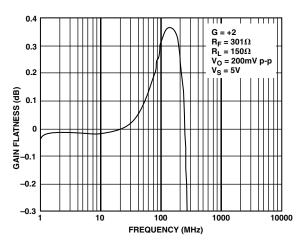
TPC 2. Large Signal Frequency Response; G = +2



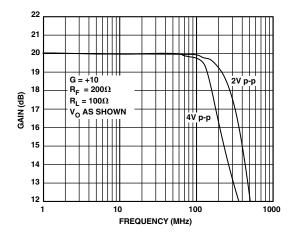
TPC 3. Large Signal Frequency Response vs. Temperature; G = +2



TPC 4. Gain Flatness; G = +2

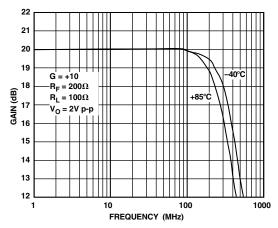


TPC 5. Gain Flatness; G = +2;  $V_S = 5 V$ 

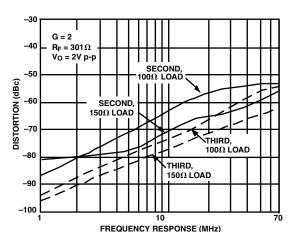


TPC 6. Large Signal Frequency Response; G = +10

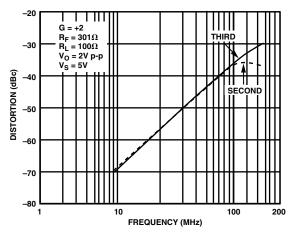
REV. F \_5\_



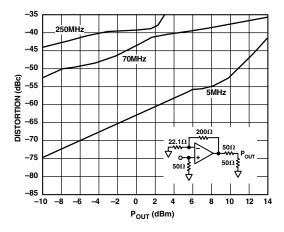
TPC 7. Large Signal Frequency Response vs. Temperature; G = +10



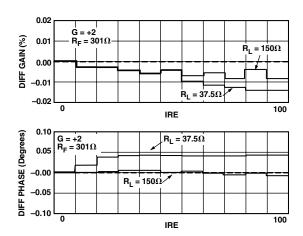
TPC 8. Distortion vs. Frequency; G = +2



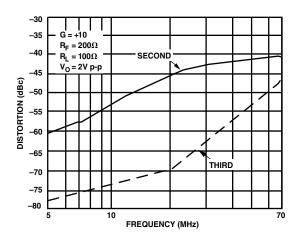
TPC 9. Distortion vs. Frequency; G = +2;  $V_S = 5 V$ 



TPC 10. Second Harmonic Distortion vs.  $P_{OUT}$ ; (G = +10)

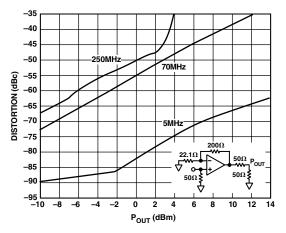


TPC 11. Differential Gain and Phase

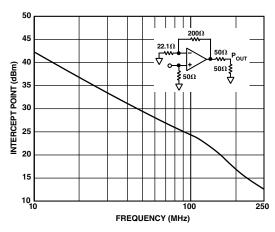


TPC 12. Distortion vs. Frequency; G = +10

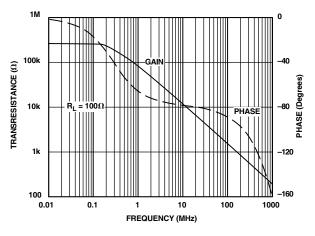
-6- REV. F



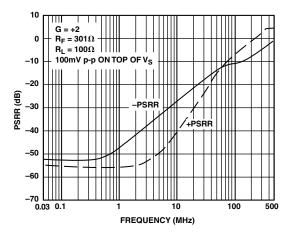
TPC 13. Third Harmonic Distortion vs.  $P_{OUT}$ ; (G = +10)



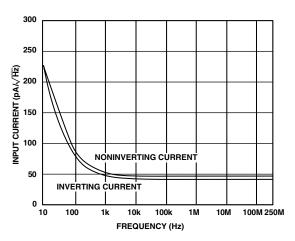
TPC 14. Two Tone, Third Order IMD Intercept vs. Frequency; G = +10



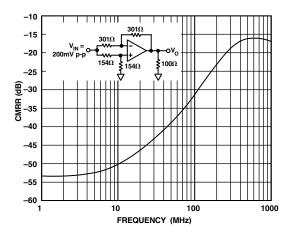
TPC 15. Transresistance and Phase vs. Frequency



TPC 16. PSRR vs. Frequency

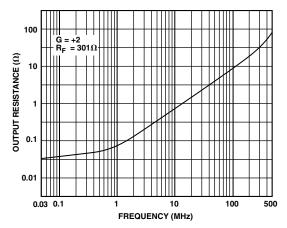


TPC 17. Current Noise vs. Frequency

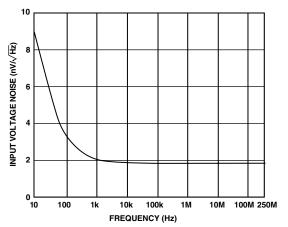


TPC 18. CMRR vs. Frequency

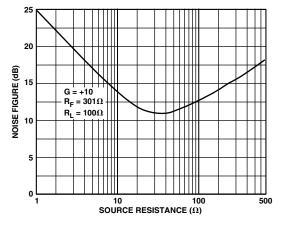
REV. F -7-



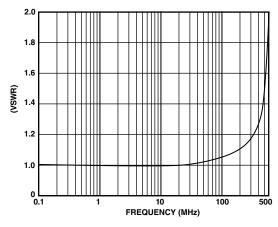
TPC 19. Output Resistance vs. Frequency



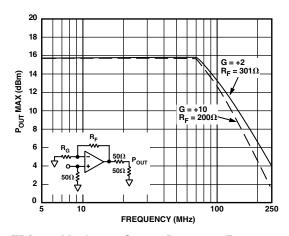
TPC 20. Voltage Noise vs. Frequency



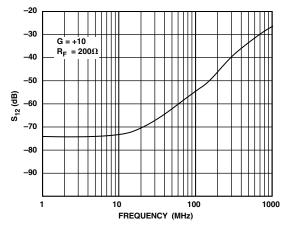
TPC 21. Noise Figure



TPC 22. Input VSWR; G = +10

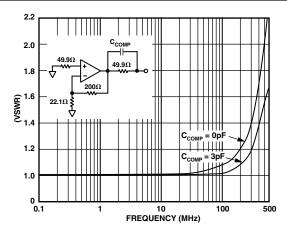


TPC 23. Maximum Output Power vs. Frequency

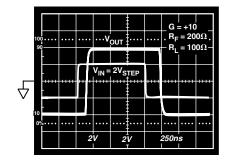


TPC 24. Reverse Isolation  $(S_{12})$ ; G = +10

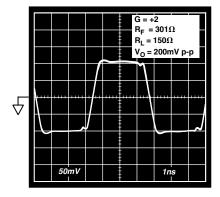
-8- REV. F



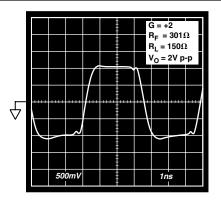
TPC 25. Output VSWR; G = +10



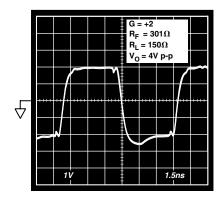
TPC 26. Overdrive Recovery; G = +10



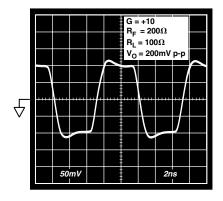
TPC 27. 2 V Transient Response; G = +2



TPC 28. 2 V Transient Response; G = +2

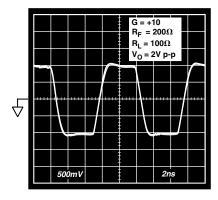


TPC 29. 4 V Transient Response; G = +2

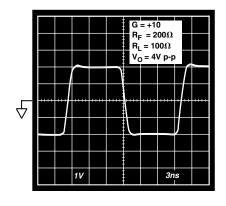


TPC 30. Small Signal Transient Response; G = +10

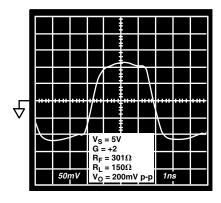
REV. F \_9\_



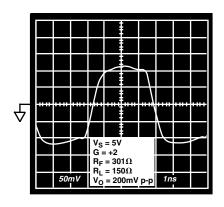
TPC 31. 2 V Transient Response; G = +10



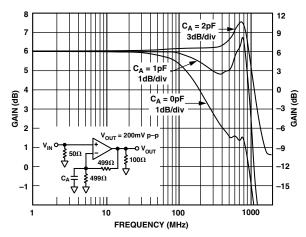
TPC 32. 4 V Transient Response; G = +10



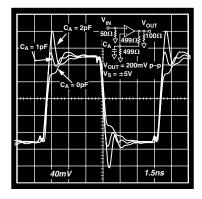
TPC 33. Small Signal Transient Response;  $V_S = 5 V$ ; G = +2



TPC 34. 2 V Transient Response;  $V_S = 5 V$ ; G = +2

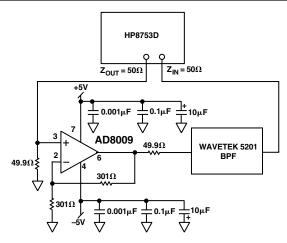


TPC 35. Small Signal Frequency Response vs. Parasitic Capacitance

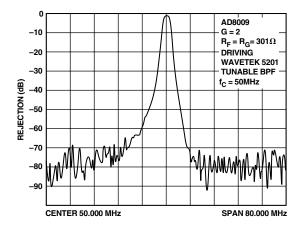


TPC 36. Small Signal Pulse Response vs. Parasitic Capacitance

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TPC 37. AD8009 Driving a Band-Pass RF Filter



TPC 38. Frequency Response of Band-Pass Filter Circuit

#### **APPLICATIONS**

All current feedback op amps are affected by stray capacitance on their –INPUT. TPCs 35 and 36 illustrate the AD8009's response to such capacitance.

TPC 35 shows the bandwidth can be extended by placing a capacitor in parallel with the gain resistor. The small signal pulse response corresponding to such an increase in capacitance/bandwidth is shown in TPC 36.

As a practical consideration, the higher the capacitance on the –INPUT to GND, the higher  $R_{\rm F}$  needs to be to minimize peaking/ringing.

#### **RF Filter Driver**

The output drive capability, wide bandwidth, and low distortion of the AD8009 are well suited for creating gain blocks that can drive RF filters. Many of these filters require that the input be driven by a 50  $\Omega$  source, while the output must be terminated in 50  $\Omega$  for the filters to exhibit their specified frequency response.

TPC 37 shows a circuit for driving and measuring the frequency response of a filter, a Wavetek 5201 tunable band-pass filter that is tuned to a 50 MHz center frequency. The HP8753D network provides a stimulus signal for the measurement. The analyzer has a 50  $\Omega$  source impedance that drives a cable that is terminated in 50  $\Omega$  at the high impedance noninverting input of the AD8009.

The AD8009 is set at a gain of +2. The series 50  $\Omega$  resistor at the output, along with the 50  $\Omega$  termination provided by the filter and its termination, yield an overall unity gain for the measured path. The frequency response plot of TPC 38 shows the circuit to have an insertion loss of 1.3 dB in the pass band and about 75 dB rejection in the stop band.

REV. F –11–

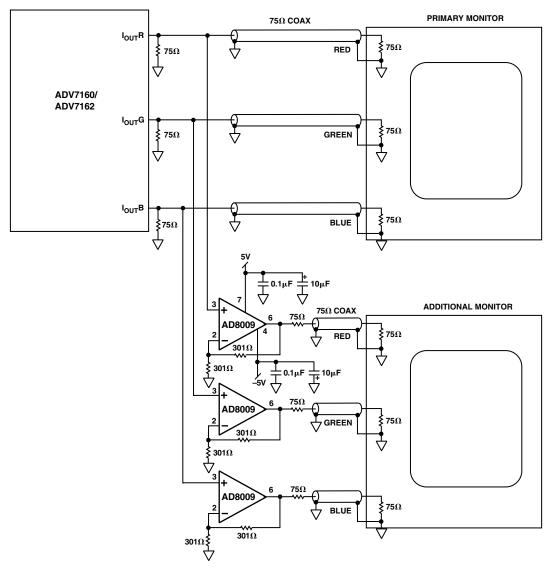


Figure 4. Driving an Additional High Resolution Monitor Using Three AD8009s

#### **RGB Monitor Driver**

High resolution computer monitors require very high full power bandwidth signals to maximize their display resolution. The RGB signals that drive these monitors are generally provided by a current-out RAMDAC that can directly drive a 75  $\Omega$  doubly terminated line.

There are times when the same output wants to be delivered to additional monitors. The termination provided internally by each monitor prohibits the ability to simply connect a second monitor in parallel with the first. Additional buffering must be provided.

Figure 4 shows a connection diagram for two high resolution monitors being driven by an ADV7160 or ADV7162, a 220 MHz (Megapixel per second) triple RAMDAC. This pixel rate requires a driver whose full power bandwidth is at least half the pixel rate or 110 MHz. This is to provide good resolution for a worst-case signal that swings between zero scale and full scale on adjacent pixels.

The primary monitor is connected in the conventional fashion with a 75  $\Omega$  termination to ground at each end of the 75  $\Omega$  cable. Sometimes this configuration is called "doubly terminated" and is used when the driver is a high output impedance current source.

For the additional monitor, each of the RGB signals close to the RAMDAC output is applied to a high input impedance, noninverting input of an AD8009 that is configured for a gain of  $\pm 2$ . The outputs each drive a series 75  $\Omega$  resistor, cable, and termination resistor in the monitor that divides the output signal by two, thus providing an overall unity gain. This scheme is referred to as "back termination" and is used when the driver is a low output impedance voltage source. Back termination requires that the voltage of the signal be double the value that the monitor sees. Double termination requires that the output current be double the value that flows in the monitor termination.

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#### **Driving a Capacitive Load**

A capacitive load, like that presented by some A/D converters, can sometimes be a challenge for an op amp to drive depending on the architecture of the op amp. Most of the problem is caused by the pole created by the output impedance of the op amp and the capacitor that is driven. This creates extra phase shift that can eventually cause the op amp to become unstable.

One way to prevent instability and improve settling time when driving a capacitor is to insert a resistor in series between the op amp output and the capacitor. The feedback resistor is still connected directly to the output of the op amp, while the series resistor provides some isolation of the capacitive load from the op amp output.

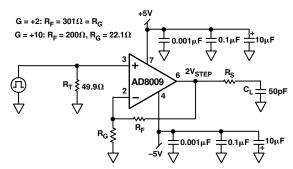


Figure 5. Capacitive Load Drive Circuit

Figure 5 shows such a circuit with an AD8009 driving a 50 pF load. With  $R_S$  = 0, the AD8009 circuit will be unstable. For a gain of +2 and +10, it was found experimentally that setting  $R_S$  to 42.2  $\Omega$  will minimize the 0.1% settling time with a 2 V step at the output. The 0.1% settling time was measured to be 40 ns with this circuit.

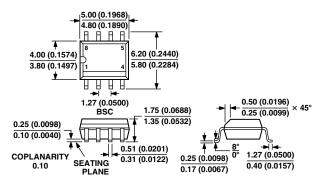
For smaller capacitive loads, a smaller  $R_S$  will yield optimal settling time, while a larger  $R_S$  will be required for larger capacitive loads. Of course, a larger capacitance will always require more time for settling to a given accuracy than a smaller one, and this will be lengthened by the increase in  $R_S$  required. At best, a given RC combination will require about seven time constants by itself to settle to 0.1%, so a limit will be reached where too large a capacitance cannot be driven by a given op amp and still meet the system's required settling time specification.

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#### **OUTLINE DIMENSIONS**

# 8-Lead Standard Small Outline Package [SOIC] (R-8)

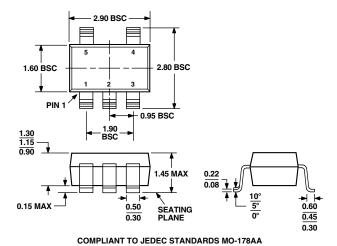
Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

# 5-Lead Small Outline Transistor Package [SOT-23] (RT-5)

Dimensions shown in millimeters



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# **Revision History**

Location	Page
9/04—Data Sheet changed from REV. E to REV. F.	
Changes to ORDERING GUIDE	4
Change to TPC 37	11
3/03—Data Sheet changed from REV. D to REV. E.	
Updated Data Sheet Format	Universal
Changes to FEATURES	1
Changes to Figure 2	1
Changes to SPECIFICATIONS	2
Deleted AD8009EB from ORDERING GUIDE	4
Inserted new TPC 5	5
Inserted new TPC 9	6
Inserted new TPC 12	6
Inserted new TPCs 33 and 34	10
Updated OUTLINE DIMENSIONS	14

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